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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Advanced PMU for Portable Handheld Equipment

FEATURES

- Three Step-Down DC/DC Converters
- Four Low-Dropout Linear Regulators
- Dedicated enable pins for the voltage regulators for flexible power sequencing.
- Integrated *ActivePath™* Charger
- I²C™ Serial Interface
- Minimal External Components
- Tiny 5×5mm TQFN55-40 Package
 - 0.75mm Package Height
 - Pb-Free and RoHS Compliant

GENERAL DESCRIPTION

The ACT8930 is a complete, cost effective, highly-efficient *ActivePMU™* power management solution, for portable handheld equipment such as Smartphones, Mobile Internet Devices (MID), eBooks and etc.

This device features three step-down DC/DC converters and four low-noise, low-dropout linear regulators, along with a complete battery charging solution featuring the advanced *ActivePath™* system-power selection function.

The three DC/DC converters utilize a high-efficiency, fixed-frequency (2MHz), current-mode PWM control architecture that requires a minimum number of external components. Two DC/DCs are capable of supplying up to 1100mA of output current, while the third supports up to 1300mA. All four low-dropout linear regulators are high-performance, low-noise regulators that supply up to 320mA each.

The ACT8930 is available in a compact, Pb-Free and RoHS-compliant TQFN55-40 package.

SYSTEM BLOCK DIAGRAM

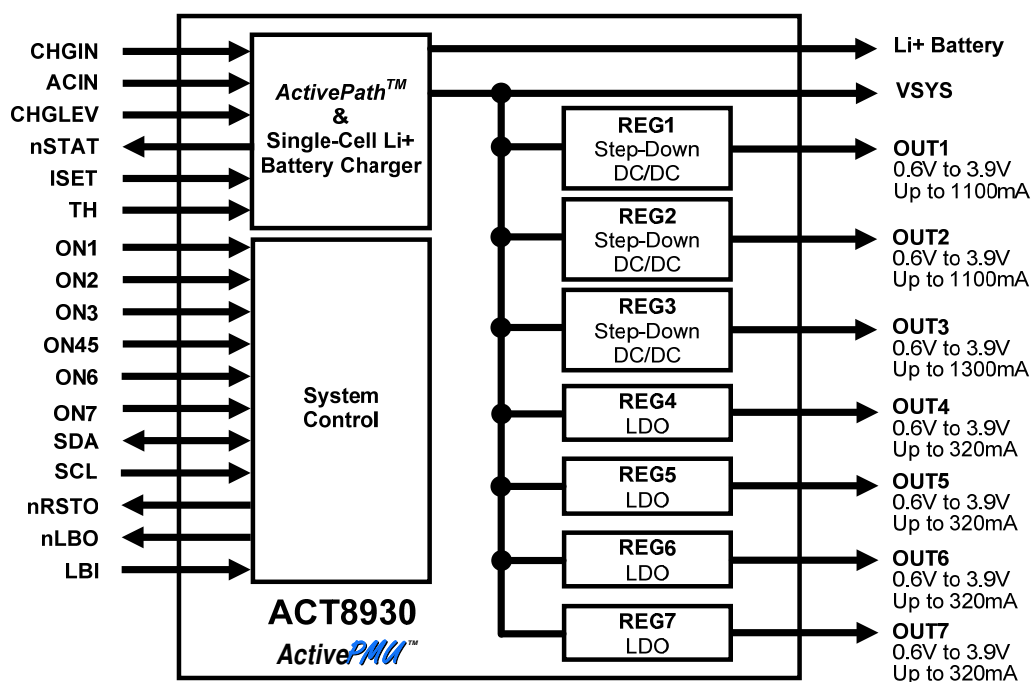
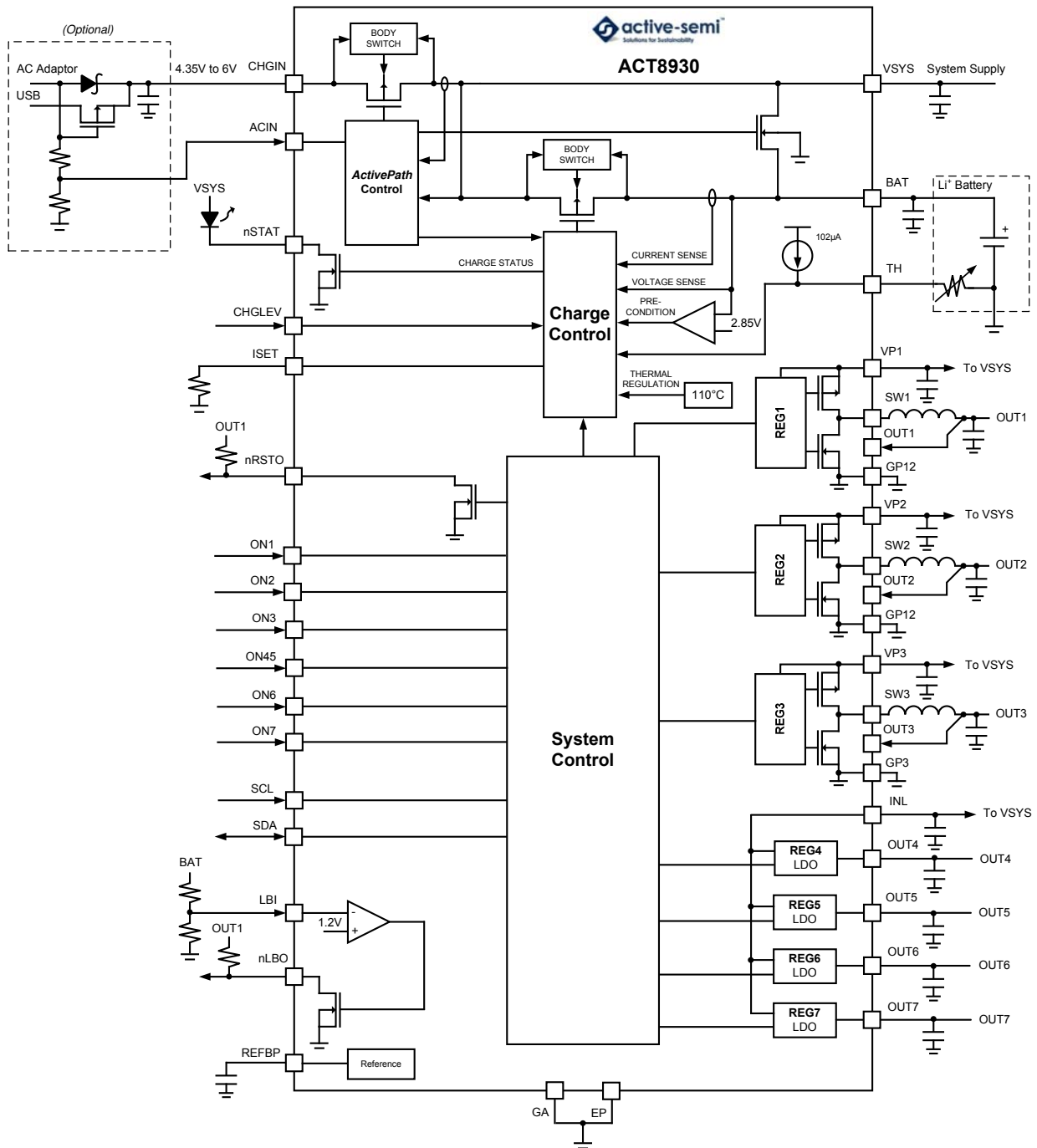


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FUNCTIONAL BLOCK DIAGRAM

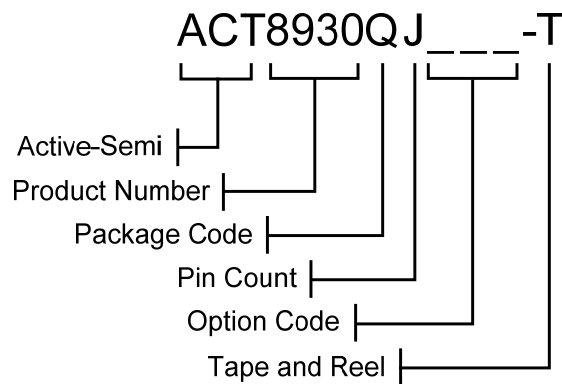


ORDERING INFORMATION^{①②}

PART NUMBER	V _{OUT1}	V _{OUT2}	V _{OUT3}	V _{OUT4}	V _{OUT5}	V _{OUT6}	V _{OUT7}	PACKAGE	PINS	TEMPERATURE RANGE
ACT8930QJ133-T	3.3V	1.3V	1.3V	1.2V	1.2V	1.2V	3.3V	TQFN55-40	40	-40°C to +85°C
ACT8930QJ134-T	1.35V	3.3V	1.8V	3.3V	1.8V	3.3V	3.3V	TQFN55-40	40	-40°C to +85°C
ACT8930QJ135-T	1.8V	1.2	1.2V	1.2V	3.3V	3.3V	1.8V	TQFN55-40	40	-40°C to +85°C

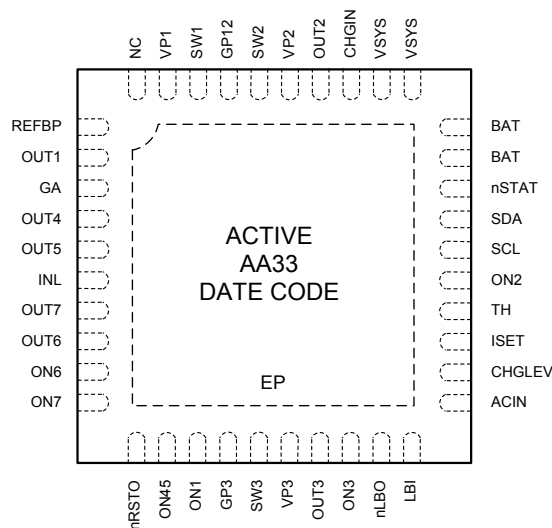
①: All Active-Semi components are RoHS Compliant and with Pb-free plating unless otherwise specified.

②: Standard product options are listed in this table. Contact factory for custom options. Minimum order quantity is 12,000 units.



PIN CONFIGURATION

TOP VIEW



Thin - QFN (TQFN55-40)

PIN DESCRIPTIONS

PIN	NAME	DESCRIPTION
1	REFBP	Reference Bypass. Connect a 0.047 μ F ceramic capacitor from REFBP to GA. This pin is discharged to GA in shutdown.
2	OUT1	Output Feedback Sense for REG1.
3	GA	Analog Ground. Connect GA directly to a quiet ground node. Connect GA, GP12 and GP3 together at a single point as close to the IC as possible.
4	OUT4	REG4 output. Capable of delivering up to 320mA of output current. Connect a 3.3 μ F ceramic capacitor from OUT4 to GA. The output is discharged to GA with 1.5k Ω resistor when disabled.
5	OUT5	REG5 output. Capable of delivering up to 320mA of output current. Connect a 3.3 μ F ceramic capacitor from OUT5 to GA. The output is discharged to GA with 1.5k Ω resistor when disabled.
6	INL	Power Input for REG4, REG5, REG6, and REG7. Bypass to GA with a high quality ceramic capacitor placed as close to the IC as possible.
7	OUT7	REG7 output. Capable of delivering up to 320mA of output current. Connect a 3.3 μ F ceramic capacitor from OUT7 to GA. The output is discharged to GA with 1.5k Ω resistor when disabled.
8	OUT6	REG6 output. Capable of delivering up to 320mA of output current. Connect a 3.3 μ F ceramic capacitor from OUT6 to GA. The output is discharged to GA with 1.5k Ω resistor when disabled.
9	ON6	Enable Input for REG6. Drive to VP1 or a logic high to enable REG6. Drive to GA to disable.
10	ON7	Enable Input for REG7. Drive to VP1 or a logic high to enable REG7. Drive to GA to disable.
11	nRSTO	Active Low Reset Output. See the <i>nRSTO Output</i> section for more information.
12	ON45	Enable Input for REG4 and REG5. Drive to VP1 or a logic high to enable REG4 and REG5. Drive to GA to disable.
13	ON1	Enable Input for REG1. Drive to VP1 or a logic high to enable REG1. Drive to GA to disable.
14	GP3	Power Ground for REG3. Connect GA, GP12, and GP3 together at a single point as close to the IC as possible.
15	SW3	Switching Node Output for REG3.
16	VP3	Power Input for REG3. Bypass to GP3 with a high quality ceramic capacitor placed as close to the IC as possible.
17	OUT3	Output Feedback Sense for REG3.
18	ON3	Enable Input for REG3. Drive to VP1 or a logic high to enable REG3. Drive to GA to disable.
19	nLBO	Low Battery Indicator Output. nLBO is asserted low whenever the voltage at LBI is lower than 1.2V, and is high-Z otherwise. See the <i>Precision Voltage Detector</i> section for more information.
20	LBI	Low Battery Input. The input voltage is compared to 1.2V and the output of this comparison drives nLBO. See the <i>Precision Voltage Detector</i> section for more information.
21	ACIN	AC Input Supply Detection. See the <i>Charge Current Programming</i> section for more information.
22	CHGLEV	Charge Current Selection Input. See the <i>Charge Current Programming</i> section for more information.

PIN DESCRIPTIONS CONT'D

PIN	NAME	DESCRIPTION
23	ISET	Charge Current Set. Program the charge current by connecting a resistor (R_{ISET}) between ISET and GA. See the <i>Charge Current Programming</i> section for more information.
24	TH	Temperature Sensing Input. Connect to battery thermistor. TH is pulled up with a 102 μ A (typ) current internally. See the <i>Battery Temperature Monitoring</i> section for more information.
25	ON2	Enable Input for REG2. Drive to VP1 or a logic high to enable REG2. Drive to GA to disable.
26	SCL	Clock Input for I ² C Serial Interface.
27	SDA	Data Input for I ² C Serial Interface. Data is read on the rising edge of SCL.
28	nSTAT	Active-Low Open-Drain Charger Status Output. nSTAT has a 8mA (typ) current limit, allowing it to directly drive an indicator LED without additional external components. See the <i>Charge Status Indicator</i> section for more information.
29, 30	BAT	Battery Charger Output. Connect this pin directly to the battery anode (+ terminal)
31, 32	VSYS	System Output Pin. Bypass to GA with a 10 μ F or larger ceramic capacitor.
33	CHGIN	Power Input for the Battery Charger. Bypass CHGIN to GA with a capacitor placed as close to the IC as possible. The battery charger is automatically enabled when a valid voltage is present on CHGIN .
34	OUT2	Output Feedback Sense for REG2.
35	VP2	Power Input for REG2. Bypass to GP12 with a high quality ceramic capacitor placed as close to the IC as possible.
36	SW2	Switching Node Output for REG2.
37	GP12	Power Ground for REG1 and REG2. Connect GA, GP12 and GP3 together at a single point as close to the IC as possible.
38	SW1	Switching Node Output for REG1.
39	VP1	Power Input for REG1. Bypass to GP12 with a high quality ceramic capacitor placed as close to the IC as possible.
40	NC	No Connect. Not internally connected.
EP	EP	Exposed Pad. Must be soldered to ground on PCB.

ABSOLUTE MAXIMUM RATINGS^①

PARAMETER	VALUE	UNIT
VP1, VP2 to GP12 VP3 to GP3	-0.3 to +6	V
BAT, VSYS, INL to GA	-0.3 to +6	V
CHGIN to GA	-0.3 to +14	V
SW1, OUT1 to GP12	-0.3 to ($V_{VP1} + 0.3$)	V
SW2, OUT2 to GP12	-0.3 to ($V_{VP2} + 0.3$)	V
SW3, OUT3 to GP3	-0.3 to ($V_{VP3} + 0.3$)	V
nLBO, nRSTO, nSTAT to GA	-0.3 to +6	V
ON45, ON1, ON6, ACIN, CHGLEV, ISET, LBI, ON7, ON3, REFBP, SCL, SDA, TH, ON2 to GA	-0.3 to ($V_{SYS} + 0.3$)	V
OUT4, OUT5, OUT6, OUT7 to GA	-0.3 to ($V_{INL} + 0.3$)	V
GP12, GP3 to GA	-0.3 to +0.3	V
Operating Ambient Temperature	-40 to 85	°C
Maximum Junction Temperature	125	°C
Maximum Power Dissipation TQFN55-40 (Thermal Resistance $\theta_{JA} = 30^{\circ}\text{C/W}$)	2.7	W
Storage Temperature	-65 to 150	°C
Lead Temperature (Soldering, 10 sec)	300	°C

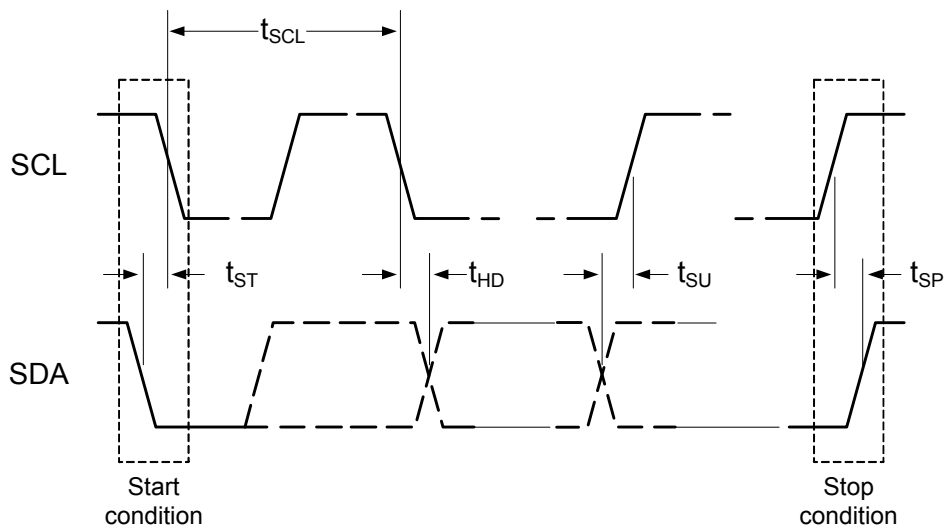
①: Do not exceed these limits to prevent damage to the device. Exposure to absolute maximum rating conditions for long periods may affect device reliability.

I²C INTERFACE ELECTRICAL CHARACTERISTICS

(V_{VSYS} = 3.6V, T_A = 25°C, unless otherwise specified.)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SCL, SDA Input Low	V _{VSYS} = 3.1V to 5.5V, T _A = -40°C to 85°C			0.35	V
SCL, SDA Input High	V _{VSYS} = 3.1V to 5.5V, T _A = -40°C to 85°C	1.55			V
SDA Leakage Current				1	μA
SCL Leakage Current			8	18	μA
SDA Output Low	I _{OL} = 5mA			0.35	V
SCL Clock Period, t _{SCL}		1.5			μs
SDA Data Setup Time, t _{SU}		100			ns
SDA Data Hold Time, t _{HD}		300			ns
Start Setup Time, t _{ST}	For Start Condition	100			ns
Stop Setup Time, t _{SP}	For Stop Condition	100			ns

Figure 1:
I²C Compatible Serial Bus Timing



GLOBAL REGISTER MAP

OUTPUT	ADDRESS		BITS							
			D7	D6	D5	D4	D3	D2	D1	D0
SYS	0x00	NAME	TRST	nSYSMODE	Reserved	nSYSSTAT	SYSLEV[3]	SYSLEV[2]	SYSLEV[1]	SYSLEV[0]
		DEFAULT ^①	0	1	0	R	0	1	1	1
SYS	0x01	NAME	Reserved	Reserved	Reserved	Reserved	SCRATCH	SCRATCH	SCRATCH	SCRATCH
		DEFAULT ^①	0	0	0	0	0	0	0	0
REG1	0x20	NAME	Reserved	Reserved	VSET[5]	VSET[4]	VSET[3]	VSET[2]	VSET[1]	VSET[0]
		DEFAULT ^①	0	0	1	1	1	0	0	1
REG1	0x22	NAME	ON	PHASE	MODE	Reserved	Reserved	Reserved	Reserved	OK
		DEFAULT ^①	0	0	0	0	1	1	0	R
REG2	0x30	NAME	Reserved	Reserved	VSET[5]	VSET[4]	VSET[3]	VSET[2]	VSET[1]	VSET[0]
		DEFAULT ^①	0	0	0	1	1	0	1	0
REG2	0x32	NAME	ON	PHASE	MODE	Reserved	Reserved	Reserved	Reserved	OK
		DEFAULT ^①	0	0	0	0	1	1	0	R
REG3	0x40	NAME	Reserved	Reserved	VSET[5]	VSET[4]	VSET[3]	VSET[2]	VSET[1]	VSET[0]
		DEFAULT ^①	0	0	0	1	1	0	1	0
REG3	0x42	NAME	ON	Reserved	MODE	Reserved	Reserved	Reserved	Reserved	OK
		DEFAULT ^①	0	0	0	0	0	0	0	R
REG4	0x50	NAME	Reserved	Reserved	VSET[5]	VSET[4]	VSET[3]	VSET[2]	VSET[1]	VSET[0]
		DEFAULT ^①	0	0	0	1	1	0	0	0
REG4	0x51	NAME	ON	DIS	LOWIQ	Reserved	Reserved	Reserved	Reserved	OK
		DEFAULT ^①	0	1	0	0	0	0	0	R
REG5	0x54	NAME	Reserved	Reserved	VSET[5]	VSET[4]	VSET[3]	VSET[2]	VSET[1]	VSET[0]
		DEFAULT ^①	0	0	0	1	1	0	0	0
REG5	0x55	NAME	ON	DIS	LOWIQ	Reserved	Reserved	Reserved	Reserved	OK
		DEFAULT ^①	0	1	0	0	0	0	0	R
REG6	0x60	NAME	Reserved	Reserved	VSET[5]	VSET[4]	VSET[3]	VSET[2]	VSET[1]	VSET[0]
		DEFAULT ^①	0	0	0	1	1	0	0	0
REG6	0x61	NAME	ON	DIS	LOWIQ	Reserved	Reserved	Reserved	Reserved	OK
		DEFAULT ^①	0	1	0	0	0	0	0	R
REG7	0x64	NAME	Reserved	Reserved	VSET[5]	VSET[4]	VSET[3]	VSET[2]	VSET[1]	VSET[0]
		DEFAULT ^①	0	0	1	1	1	0	0	1
REG7	0x65	NAME	ON	DIS	LOWIQ	Reserved	Reserved	Reserved	Reserved	OK
		DEFAULT ^①	0	1	0	0	0	0	0	R
APCH	0x70	NAME	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved
		DEFAULT ^①	0	1	0	1	0	0	0	0
APCH	0x71	NAME	SUSCHG	Reserved	TOTTIMO[1]	TOTTIMO[0]	PRETIMO[1]	PRETIMO[0]	OVPSET[1]	OVPSET[0]
		DEFAULT ^①	0	0	1	0	1	0	0	0
APCH	0x78	NAME	Reserved	Reserved	Reserved	Reserved	TIMRDAT	TEMPDAT	INDAT	CHGDAT
		DEFAULT ^①	0	0	0	0	R	R	R	R
APCH	0x7A	NAME	Reserved	Reserved	CSTATE[0]	CSTATE[1]	Reserved	Reserved	ACINSTAT	Reserved
		DEFAULT ^①	0	0	R	R	R	R	R	R

①: Default values of ACT8930QJ133-T.

②: All bits are automatically cleared to default values when the input power is removed or falls below the system UVLO.

REGISTER AND BIT DESCRIPTIONS

Table 1:
Global Register Map

OUTPUT	ADDRESS	BIT	NAME	ACCESS	DESCRIPTION
SYS	0x00	[7]	TRST	R/W	Reset Timer Setting. Defines the reset time-out threshold. Reset time-out is 65ms when value is 1, reset time-out is 260ms when value is 0. See <i>nRSTO Output</i> section for more information.
SYS	0x00	[6]	nSYSMODE	R/W	SYSLEV Mode Select. Defines the response to the SYSLEV voltage detector, 1: Do nothing, 0: automatic shutdown when V_{VSYS} falls below the programmed SYSLEV threshold.
SYS	0x00	[5]	-	R	Reserved.
SYS	0x00	[4]	nSYSSTAT	R	System Voltage Status. Value is 1 when V_{VSYS} is lower than the SYSLEV voltage threshold, value is 0 when V_{VSYS} is higher than the system voltage detection threshold.
SYS	0x00	[3:0]	SYSLEV	R/W	System Voltage Detect Threshold. Defines the SYSLEV voltage threshold. See the <i>Programmable System Voltage Monitor</i> section for more information.
SYS	0x01	[7:4]	-	R/W	Reserved.
SYS	0x01	[3:0]	SCRATCH	R/W	Scratchpad Bits. Non-functional bits, maybe be used by user to store system status information. Volatile bits, which are cleared when system voltage falls below UVLO threshold.
REG1	0x20	[7:6]	-	R	Reserved.
REG1	0x20	[5:0]	VSET	R/W	Output Voltage Selection. See the <i>Output Voltage Programming</i> section for more information.
REG1	0x22	[7]	ON	R/W	Regulator Enable Bit. Set bit to 1 to enable the regulator, clear bit to 0 to disable the regulator.
REG1	0x22	[6]	PHASE	R/W	Regulator Phase Control. Set bit to 1 for the regulator to operate 180° out of phase with the oscillator, clear bit to 0 for the regulator to operate in phase with the oscillator.
REG1	0x22	[5]	MODE	R/W	Regulator Mode Select. Set bit to 1 for fixed-frequency PWM under all load conditions, clear bit to 0 to transit to power-savings mode under light-load conditions.
REG1	0x22	[4:1]	-	R	Reserved.
REG1	0x22	[0]	OK	R	Regulator Power-OK Status. Value is 1 when output voltage exceeds the power-OK threshold, value is 0 otherwise.
REG2	0x30	[7:6]	-	R	Reserved.
REG2	0x30	[5:0]	VSET	R/W	Output Voltage Selection. See the <i>Output Voltage Programming</i> section for more information.
REG2	0x32	[7]	ON	R/W	Regulator Enable Bit. Set bit to 1 to enable the regulator, clear bit to 0 to disable the regulator.
REG2	0x32	[6]	PHASE	R/W	Regulator Phase Control. Set bit to 1 for the regulator to operate 180° out of phase with the oscillator, clear bit to 0 for the regulator to operate in phase with the oscillator.

REGISTER AND BIT DESCRIPTIONS CONT'D

OUTPUT	ADDRESS	BIT	NAME	ACCESS	DESCRIPTION
REG2	0x32	[5]	MODE	R/W	Regulator Mode Select. Set bit to 1 for fixed-frequency PWM under all load conditions, clear bit to 0 to transit to power-savings mode under light-load conditions.
REG2	0x32	[4:1]	-	R	Reserved.
REG2	0x32	[0]	OK	R	Regulator Power-OK Status. Value is 1 when output voltage exceeds the power-OK threshold, value is 0 otherwise.
REG3	0x40	[7:6]	-	R	Reserved.
REG3	0x40	[5:0]	VSET	R/W	Output Voltage Selection. See the <i>Output Voltage Programming</i> section for more information.
REG3	0x42	[7]	ON	R/W	Regulator Enable Bit. Set bit to 1 to enable the regulator, clear bit to 0 to disable the regulator.
REG3	0x42	[6]	-	R	Reserved.
REG3	0x42	[5]	MODE	R/W	Regulator Mode Select. Set bit to 1 for fixed-frequency PWM under all load conditions, clear bit to 0 to transit to power-savings mode under light-load conditions.
REG3	0x42	[4:1]	-	R	Reserved.
REG3	0x42	[0]	OK	R	Regulator Power-OK Status. Value is 1 when output voltage exceeds the power-OK threshold, value is 0 otherwise.
REG4	0x50	[7:6]	-	R	Reserved.
REG4	0x50	[5:0]	VSET	R/W	Output Voltage Selection. See the <i>Output Voltage Programming</i> section for more information.
REG4	0x51	[7]	ON	R/W	Regulator Enable Bit. Set bit to 1 to enable the regulator, clear bit to 0 to disable the regulator.
REG4	0x51	[6]	DIS	R/W	Output Discharge Control. When activated, LDO output is discharged to GA through 1.5kΩ resistor when in shutdown. Set bit to 1 to enable output voltage discharge in shutdown, clear bit to 0 to disable this function.
REG4	0x51	[5]	LOWIQ	R/W	LDO Low-IQ Mode Control. Set bit to 1 for low-power operating mode, clear bit to 0 for normal mode.
REG4	0x51	[4:1]	-	R	Reserved.
REG4	0x51	[0]	OK	R	Regulator Power-OK Status. Value is 1 when output voltage exceeds the power-OK threshold, value is 0 otherwise.
REG5	0x54	[7:6]	-	R	Reserved.
REG5	0x54	[5:0]	VSET	R/W	Output Voltage Selection. See the <i>Output Voltage Programming</i> section for more information.
REG5	0x55	[7]	ON	R/W	Regulator Enable Bit. Set bit to 1 to enable the regulator, clear bit to 0 to disable the regulator.
REG5	0x55	[6]	DIS	R/W	Output Discharge Control. When activated, LDO output is discharged to GA through 1.5kΩ resistor when in shutdown. Set bit to 1 to enable output voltage discharge in shutdown, clear bit to 0 to disable this function.
REG5	0x55	[5]	LOWIQ	R/W	LDO Low-IQ Mode Control. Set bit to 1 for low-power operating mode, clear bit to 0 for normal mode.
REG5	0x55	[4:1]	-	R	Reserved.
REG5	0x55	[0]	OK	R	Regulator Power-OK Status. Value is 1 when output voltage exceeds the power-OK threshold, value is 0 otherwise.

REGISTER AND BIT DESCRIPTIONS CONT'D

OUTPUT	ADDRESS	BIT	NAME	ACCESS	DESCRIPTION
REG6	0x60	[7:6]	-	R	Reserved.
REG6	0x60	[5:0]	VSET	R/W	Output Voltage Selection. See the <i>Output Voltage Programming</i> section for more information.
REG6	0x61	[7]	ON	R/W	Regulator Enable Bit. Set bit to 1 to enable the regulator, clear bit to 0 to disable the regulator.
REG6	0x61	[6]	DIS	R/W	Output Discharge Control. When activated, LDO output is discharged to GA through 1.5kΩ resistor when in shutdown. Set bit to 1 to enable output voltage discharge in shutdown, clear bit to 0 to disable this function.
REG6	0x61	[5]	LOWIQ	R/W	LDO Low-IQ Mode Control. Set bit to 1 for low-power operating mode, clear bit to 0 for normal mode.
REG6	0x61	[4:1]	-	R	Reserved.
REG6	0x61	[0]	OK	R	Regulator Power-OK Status. Value is 1 when output voltage exceeds the power-OK threshold, value is 0 otherwise.
REG7	0x64	[7:6]	-	R	Reserved.
REG7	0x64	[5:0]	VSET	R/W	Output Voltage Selection. See the <i>Output Voltage Programming</i> section for more information.
REG7	0x65	[7]	ON	R/W	Regulator Enable Bit. Set bit to 1 to enable the regulator, clear bit to 0 to disable the regulator.
REG7	0x65	[6]	DIS	R/W	Output Discharge Control. When activated, LDO output is discharged to GA through 1.5kΩ resistor when in shutdown. Set bit to 1 to enable output voltage discharge in shutdown, clear bit to 0 to disable this function.
REG7	0x65	[5]	LOWIQ	R/W	LDO Low-IQ Mode Control. Set bit to 1 for low-power operating mode, clear bit to 0 for normal mode.
REG7	0x65	[4:1]	-	R	Reserved.
REG7	0x65	[0]	OK	R	Regulator Power-OK Status. Value is 1 when output voltage exceeds the power-OK threshold, value is 0 otherwise.
APCH	0x70	[7:0]	-	R/W	Reserved.
APCH	0x71	[7]	SUSCHG	R/W	Charge Suspend Control Input. Set bit to 1 to suspend charging, clear bit to 0 to allow charging to resume.
APCH	0x71	[6]	-	R/W	Reserved.
APCH	0x71	[5:4]	TOTTIMO	R/W	Total Charge Time-out Selection. See the <i>Charge Safety Timers</i> section for more information.
APCH	0x71	[3:2]	PRETIMO	R/W	Precondition Charge Time-out Selection. See the <i>Charge Safety Timers</i> section for more information.
APCH	0x71	[1:0]	OVPSET	R/W	Input Over-Voltage Protection Threshold Selection. See the <i>Input Over-Voltage Protection</i> section for more information.
APCH	0x78	[7:4]	-	R	Reserved.
APCH	0x78	[3]	TIMRDAT [Ⓞ]	R	Charge Timer Status. Value is 1 when precondition time-out or total charge time-out occurs. Value is 0 in other case.
APCH	0x78	[2]	TEMPDAT [Ⓞ]	R	Temperature Status. Value is 0 when battery temperature is outside of valid range. Value is 1 when battery temperature is inside of valid range.

Ⓞ: Valid only when CHGIN UVLO Threshold < V_{CHGIN} < CHGIN OVP Threshold.

REGISTER AND BIT DESCRIPTIONS CONT'D

OUTPUT	ADDRESS	BIT	NAME	ACCESS	DESCRIPTION
APCH	0x78	[1]	INDAT	R	Input Voltage Status. Value is 1 when a valid input at CHGIN is present. Value is 0 when a valid input at CHGIN is not present.
APCH	0x78	[0]	CHGDAT®	R	Charge State Machine Status. Value is 1 indicates the charger state machine is in EOC state, value is 0 indicates the charger state machine is in other states.
APCH	0x7A	[7:6]	-	R	Reserved.
APCH	0x7A	[5:4]	CSTATE	R	Charge State. Values indicate the current charging state. See the <i>State Machine Status</i> section for more information.
APCH	0x7A	[3:2]	-	R	Reserved.
APCH	0x7A	[1]	ACINSTAT	R	ACIN Status. Indicates the state of the ACIN input, typically in order to identify the type of input supply connected. Value is 1 when ACIN is above the 1.2V precision threshold, value is 0 when ACIN is below this threshold.
APCH	0x7A	[0]	-	R	Reserved.

SYSTEM CONTROL ELECTRICAL CHARACTERISTICS

($V_{SYS} = 3.6V$, $T_A = 25^\circ C$, unless otherwise specified.)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage Range		2.7		5.5	V
UVLO Threshold Voltage	V_{SYS} Rising	2.2	2.45	2.65	V
UVLO Hysteresis	V_{SYS} Falling		200		mV
Supply Current	All Regulators Enabled		420		μA
Shutdown Supply Current	All Regulators Disabled		8	18	μA
Oscillator Frequency		1.8	2	2.2	MHz
Logic High Input Voltage ^①		1.4			V
Logic Low Input Voltage				0.4	V
Leakage Current	$V_{nRSTO} = 4.2V$			1	μA
LBI Threshold Voltage	V_{BAT} Falling	1.03	1.2	1.31	V
LBI Hysteresis Threshold	V_{BAT} Rising		200		mV
Low Level Output Voltage ^②	$I_{SINK} = 5mA$			0.35	V
nRSTO Delay			260 ^③		ms
Thermal Shutdown Temperature	Temperature rising		160		$^\circ C$
Thermal Shutdown Hysteresis			20		$^\circ C$

①: ON1, ON3, ON3, ON45, ON6, ON7 are logic inputs.

②: nLBO, nRSTO are open drain outputs.

③: Typical value shown. Actual value may vary from 227.9ms to 291.2ms.

STEP-DOWN DC/DC ELECTRICAL CHARACTERISTICS

($V_{VP1} = V_{VP2} = V_{VP3} = 3.6V$, $T_A = 25^\circ C$, unless otherwise specified.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
Operating Voltage Range		2.7		5.5	V
UVLO Threshold	Input Voltage Rising	2.5	2.6	2.7	V
UVLO Hysteresis	Input Voltage Falling		100		mV
Standby Supply Current	Regulator Enabled		65	90	μA
Shutdown Current	$V_{VP} = 5.5V$, Regulator Disabled		0	1	μA
Output Voltage Accuracy	$V_{OUT} \geq 1.2V$, $I_{OUT} = 10mA$	-1%	$V_{NOM}^{\textcircled{1}}$	1%	V
	$V_{OUT} < 1.2V$, $I_{OUT} = 10mA$	-2%	$V_{NOM}^{\textcircled{1}}$	2%	
Line Regulation	$V_{VP} = \text{Max}(V_{NOM}^{\textcircled{1}} + 1, 3.2V)$ to 5.5V		0.15		%/V
Load Regulation	$I_{OUT} = 10mA$ to $IMAX^{\textcircled{2}}$		0.0017		%/mA
Power Good Threshold	V_{OUT} Rising		93		% V_{NOM}
Power Good Hysteresis	V_{OUT} Falling		2		% V_{NOM}
Oscillator Frequency	$V_{OUT} \geq 20\%$ of V_{NOM}	1.8	2	2.2	MHz
	$V_{OUT} = 0V$		500		kHz
Soft-Start Period			400		μs
Minimum On-Time			75		ns
REG1					
Maximum Output Current		1.1			A
Current Limit		1.55	1.8	2.05	A
PMOS On-Resistance	$I_{SW1} = -100mA$		0.16		Ω
NMOS On-Resistance	$I_{SW1} = 100mA$		0.16		Ω
SW1 Leakage Current	$V_{VP1} = 5.5V$, $V_{SW1} = 0$ or 5.5V		0	1	μA
REG2					
Maximum Output Current		1.1			A
Current Limit		1.55	1.8	2.05	A
PMOS On-Resistance	$I_{SW2} = -100mA$		0.16		Ω
NMOS On-Resistance	$I_{SW2} = 100mA$		0.16		Ω
SW2 Leakage Current	$V_{VP2} = 5.5V$, $V_{SW2} = 0$ or 5.5V		0	1	μA
REG3					
Maximum Output Current		1.3			A
Current Limit		1.8	2.1	2.5	A
PMOS On-Resistance	$I_{SW3} = -100mA$		0.16		Ω
NMOS On-Resistance	$I_{SW3} = 100mA$		0.16		Ω
SW3 Leakage Current	$V_{VP3} = 5.5V$, $V_{SW3} = 0$ or 5.5V		0	1	μA

$\textcircled{1}$: V_{NOM} refers to the nominal output voltage level for V_{OUT} as defined by the *Ordering Information* section.

$\textcircled{2}$: $IMAX$ Maximum Output Current.

LOW-NOISE LDO ELECTRICAL CHARACTERISTICS

($V_{INL} = 3.6V$, $C_{OUT4} = C_{OUT5} = C_{OUT6} = C_{OUT7} = 3.3\mu F$, $LOWIQ[] = [0]$, $T_A = 25^\circ C$, unless otherwise specified.)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Operating Voltage Range		2.5		5.5	V
Output Voltage Accuracy	$V_{OUT} \geq 1.2V$, $T_A = 25^\circ C$, $I_{OUT} = 10mA$	-1%	$V_{NOM}^{\textcircled{1}}$	2%	V
	$V_{OUT} < 1.2V$, $T_A = 25^\circ C$, $I_{OUT} = 10mA$	-2%	$V_{NOM}^{\textcircled{1}}$	4%	
Line Regulation	$V_{INL} = \text{Max}(V_{OUT} + 0.5V, 3.6V)$ to 5.5V, $LOWIQ[] = [0]$		0.05		mV/V
	$V_{INL} = \text{Max}(V_{OUT} + 0.5V, 3.6V)$ to 5.5V $LOWIQ[] = [1]$		0.5		
Load Regulation	$I_{OUT} = 1mA$ to $IMAX^{\textcircled{2}}$		0.08		V/A
Power Supply Rejection Ratio	$f = 1kHz$, $I_{OUT} = 20mA$, $V_{OUT} = 1.2V$		75		dB
	$f = 10kHz$, $I_{OUT} = 20mA$, $V_{OUT} = 1.2V$		65		
Supply Current per Output	Regulator Enabled, $LOWIQ[] = [0]$		37	60	μA
	Regulator Enabled, $LOWIQ[] = [1]$		31	52	
	Regulator Disabled		0	1	
Soft-Start Period	$V_{OUT} = 2.9V$		140		μs
Power Good Threshold	V_{OUT} Rising		89		%
Power Good Hysteresis	V_{OUT} Falling		3		%
Output Noise	$I_{OUT} = 20mA$, $f = 10Hz$ to 100kHz, $V_{OUT} = 1.2V$		50		μV_{RMS}
Discharge Resistance	LDO Disabled, $DIS[] = 1$		1.5		k Ω
REG4					
Dropout Voltage ^③	$I_{OUT} = 160mA$, $V_{OUT} > 3.1V$		90	180	mV
Maximum Output Current		320			mA
Current Limit ^④	$V_{OUT} = 95\%$ of regulation voltage	370			mA
Stable C_{OUT4} Range		3.3		20	μF
REG5					
Dropout Voltage	$I_{OUT} = 160mA$, $V_{OUT} > 3.1V$		140	280	mV
Maximum Output Current		320			mA
Current Limit	$V_{OUT} = 95\%$ of regulation voltage	370			mA
Stable C_{OUT5} Range		3.3		20	μF
REG6					
Dropout Voltage	$I_{OUT} = 160mA$, $V_{OUT} > 3.1V$		90	180	mV
Maximum Output Current		320			mA
Current Limit	$V_{OUT} = 95\%$ of regulation voltage	370			mA
Stable C_{OUT6} Range		3.3		20	μF
REG7					
Dropout Voltage	$I_{OUT} = 160mA$, $V_{OUT} > 3.1V$		140	280	mV
Maximum Output Current		320			mA
Current Limit	$V_{OUT} = 95\%$ of regulation voltage	370			mA
Stable C_{OUT7} Range		3.3		20	μF

①: V_{NOM} refers to the nominal output voltage level for V_{OUT} as defined by the *Ordering Information* section.

②: $IMAX$ Maximum Output Current.

③: Dropout Voltage is defined as the differential voltage between input and output when the output voltage drops 100mV below the regulation voltage (for 3.1V output voltage or higher).

④: LDO current limit is defined as the output current at which the output voltage drops to 95% of the respective regulation voltage. Under heavy overload conditions the output current limit folds back by 30% (typ)

ActivePath™ CHARGER ELECTRICAL CHARACTERISTICS

($V_{CHGIN} = 5.0V$, $T_A = 25^\circ C$, unless otherwise specified.)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
ActivePath					
CHGIN Operating Voltage Range		4.35		6.0	V
CHGIN UVLO Threshold	CHGIN Voltage Rising	3.1	3.5	3.9	V
CHGIN UVLO Hysteresis	CHGIN Voltage Falling		0.5		V
CHGIN OVP Threshold	CHGIN Voltage Rising	6.0	6.6	7.2	V
CHGIN OVP Hysteresis	CHGIN Voltage Falling		0.4		V
CHGIN Supply Current	$V_{CHGIN} < V_{UVLO}$		35	70	μA
	$V_{CHGIN} < V_{BAT} + 50mV$, $V_{CHGIN} > V_{UVLO}$		100	200	μA
	$V_{CHGIN} > V_{BAT} + 150mV$, $V_{CHGIN} > V_{UVLO}$ Charger disabled, $I_{V_{SYS}} = 0mA$		1.3	2.0	mA
CHGIN to VSYS On-Resistance	$I_{V_{SYS}} = 100mA$		0.3		Ω
CHGIN to VSYS Current Limit	ACIN = VSYS	1.5	2		A
	ACIN = GA, CHGLEV = GA	80	90	100	mA
	ACIN = GA, CHGLEV = VSYS	400	450	500	
VSYS REGULATION					
VSYS Regulated Voltage	$I_{V_{SYS}} = 10mA$	4.45	4.6	4.8	V
nSTAT OUTPUT					
nSTAT Sink current	$V_{nSTAT} = 2V$	4	8	12	mA
nSTAT Leakage Current	$V_{nSTAT} = 4.2V$			1	μA
ACIN AND CHGLEV INPUTS					
CHGLEV Logic High Input Voltage		1.4			V
CHGLEV Logic Low Input Voltage				0.4	V
CHGLEV Leakage Current	$V_{CHGLEV} = 4.2V$			1	μA
ACIN Voltage Thresholds	ACIN voltage rising	1.03	1.2	1.31	V
ACIN Hysteresis voltage threshold	ACIN voltage falling		200		mV
ACIN Leakage Current	$V_{ACIN} = 4.2V$			1	μA
TH INPUT					
TH Pull-Up Current	$V_{CHGIN} > V_{BAT} + 100mV$, Hysteresis = 50mV	91	102	110	μA
V_{TH} Upper Temperature Voltage Threshold (V_{THH})	Hot Detect NTC Thermistor	2.44	2.51	2.58	V
V_{TH} Lower Temperature Voltage Threshold (V_{THL})	Cold Detect NTC Thermistor	0.47	0.50	0.53	V
V_{TH} Hysteresis	Upper and Lower Thresholds		30		mV

ActivePath™ CHARGER ELECTRICAL CHARACTERISTICS CONT'D

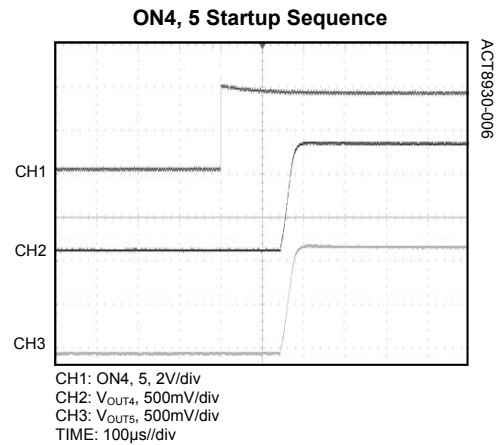
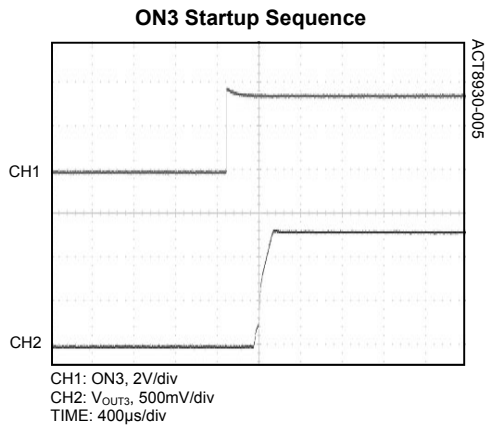
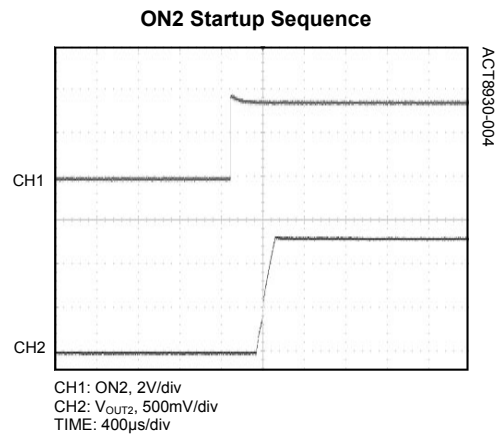
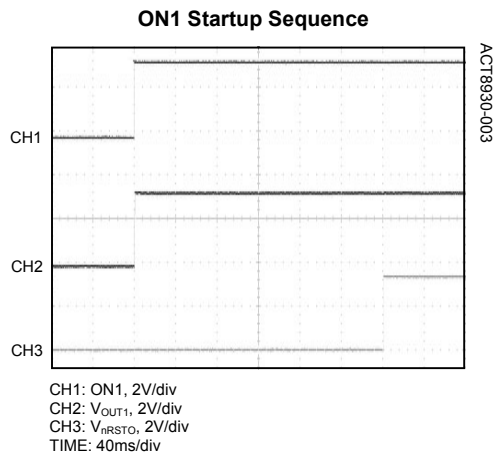
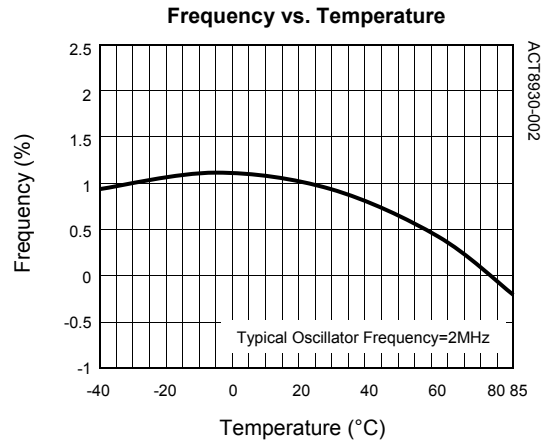
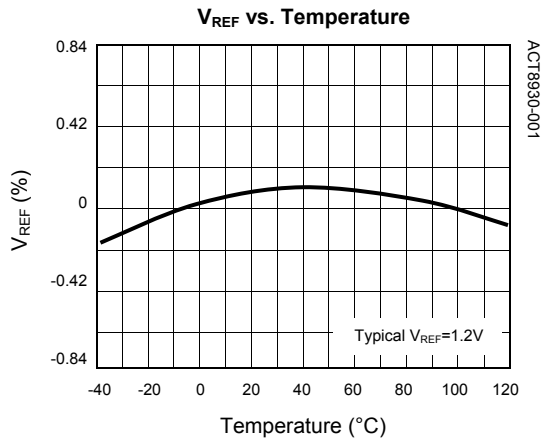
(V_{CHGIN} = 5.0V, T_A = 25°C, unless otherwise specified.)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
CHARGER						
BAT Reverse Leakage Current	V _{CHGIN} = 0V, V _{BAT} = 4.2V, I _{VSYS} = 0mA		8		μA	
BAT to VSYS On-Resistance			70		mΩ	
ISET Pin Voltage	Fast Charge		1.2		V	
	Precondition		0.13			
Charge Termination Voltage	T _A = -20°C to 70°C	4.179	4.2	4.221	V	
	T _A = -40°C to 85°C	4.170	4.2	4.230		
Charge Current	V _{BAT} = 3.8V, R _{ISET} = 6.8k	ACIN = VSYS, CHGLEV = VSYS	-10%	I _{CHG} ^①	+10%	mA
		ACIN = VSYS, CHGLEV = GA	-10%	I _{CHG} /5	+10%	
		ACIN = GA, CHGLEV = VSYS	400	450	500	
		ACIN = GA, CHGLEV = GA	80	90	100	
Precondition Charge Current	V _{BAT} = 2.7V, R _{ISET} = 6.8k	ACIN = VSYS, CHGLEV = VSYS	10% I _{CHG}		mA	
		ACIN = VSYS, CHGLEV = GA	10% I _{CHG}			
		ACIN = GA, CHGLEV = VSYS	45			
		ACIN = GA, CHGLEV = GA	45			
Precondition Threshold Voltage	V _{BAT} Voltage Rising	2.75	2.85	3.0	V	
Precondition Threshold Hysteresis	V _{BAT} Voltage Falling		150		mV	
END-OF-CHARGE Current Threshold	V _{BAT} = 4.15V	ACIN = VSYS, CHGLEV = VSYS	10% I _{CHG}		mA	
		ACIN = VSYS, CHGLEV = GA	10% I _{CHG}			
		ACIN = GA, CHGLEV = VSYS	45			
		ACIN = GA, CHGLEV = GA	45			
Charge Restart Threshold	V _{VSYS} - V _{BAT} , V _{BAT} Falling	190	205	220	mV	
Precondition Safety Timer	PRETIMO[] = 10		80		min	
Total Safety Timer	TOTTIMO[] = 10		5		hr	
Thermal Regulation Threshold			100		°C	

①: R_{ISET} (kΩ) = 2336 × (1V/I_{CHG} (mA)) - 0.205

TYPICAL PERFORMANCE CHARACTERISTICS

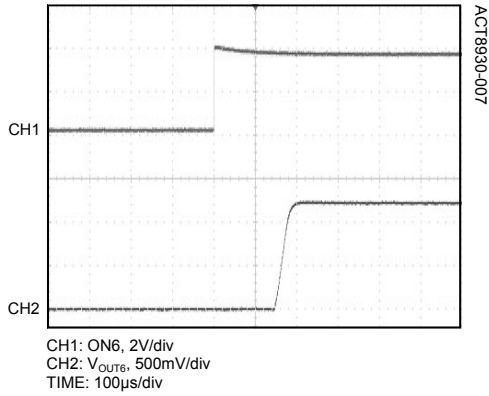
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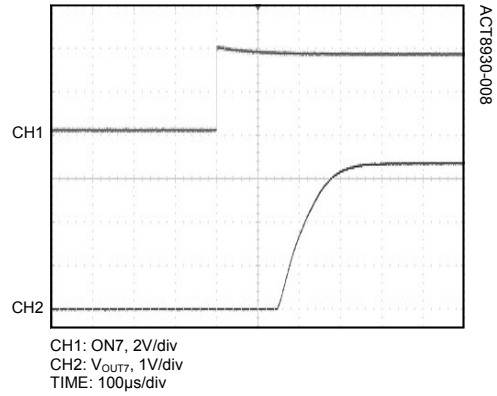
TYPICAL PERFORMANCE CHARACTERISTICS CONT'D

($T_A = 25^\circ\text{C}$, unless otherwise specified.)

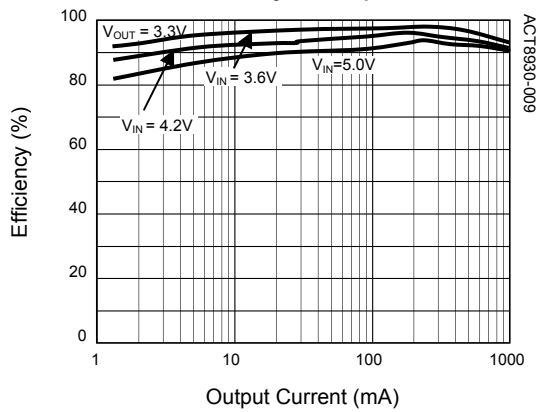
ON6 startup sequence



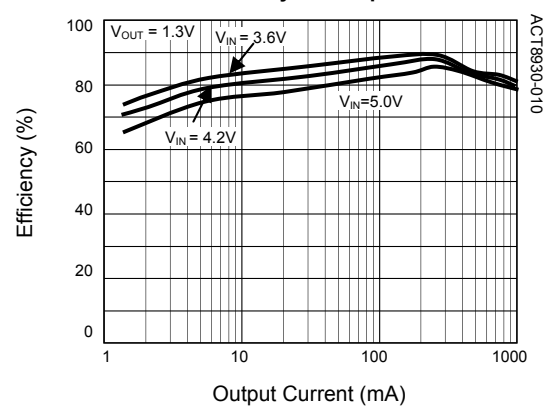
ON7 startup sequence



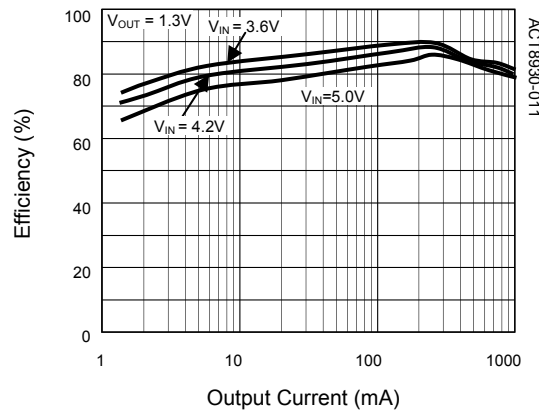
REG1 Efficiency vs. Output Current



REG2 Efficiency vs. Output Current

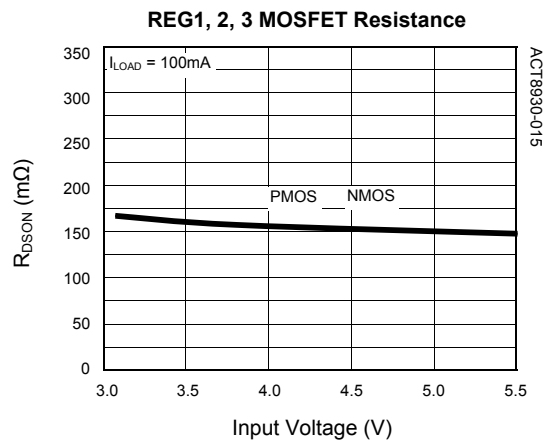
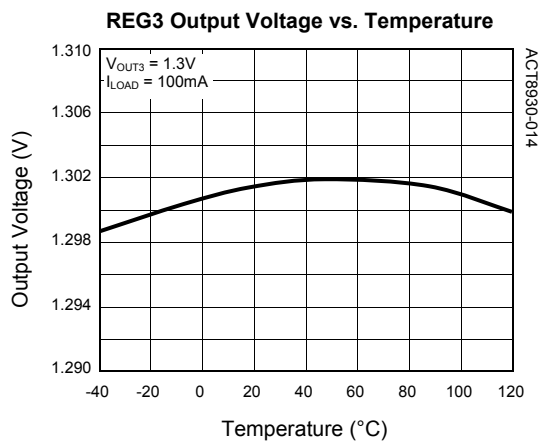
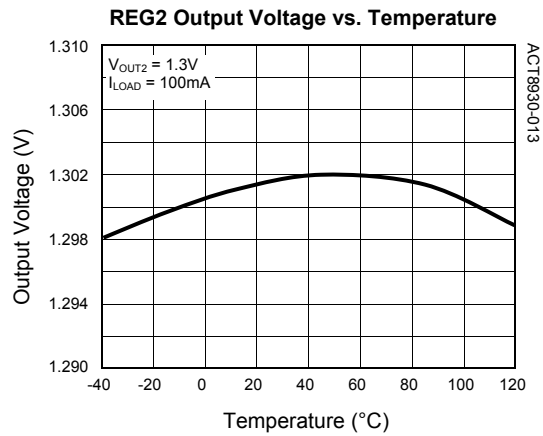
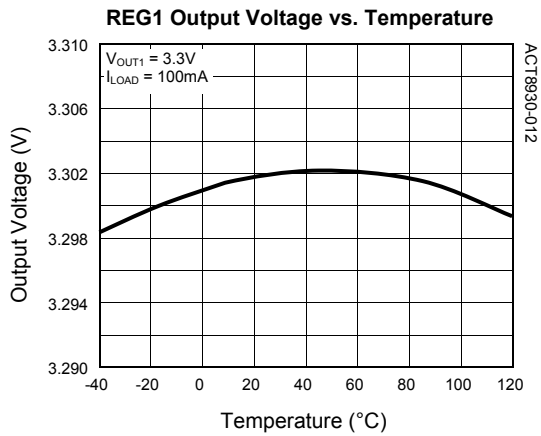


REG3 Efficiency vs. Output Current



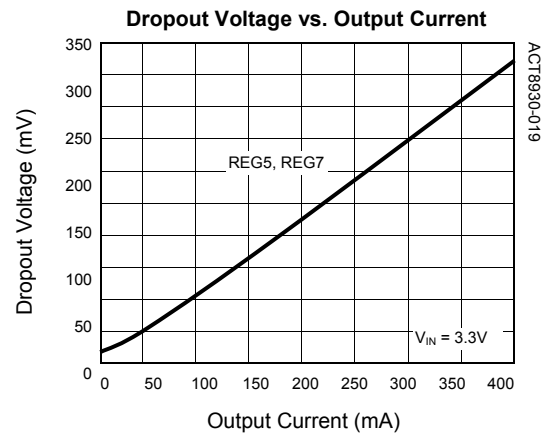
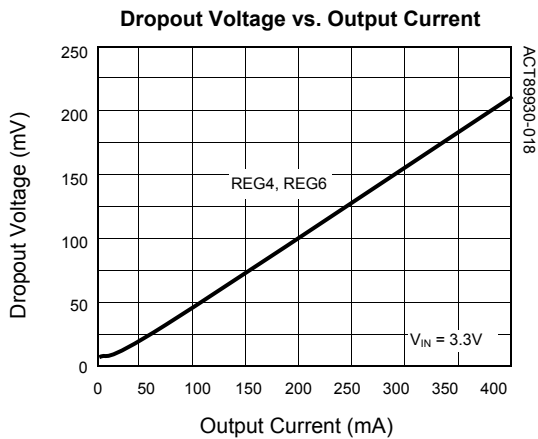
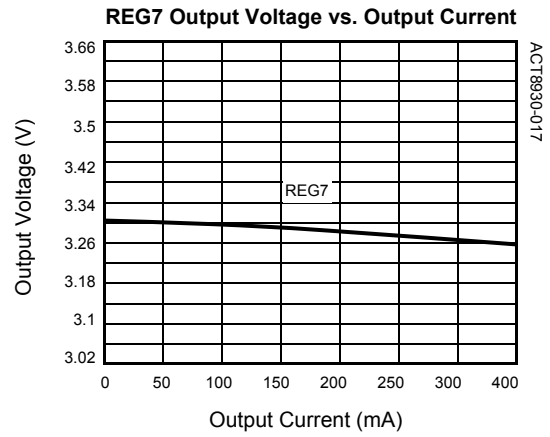
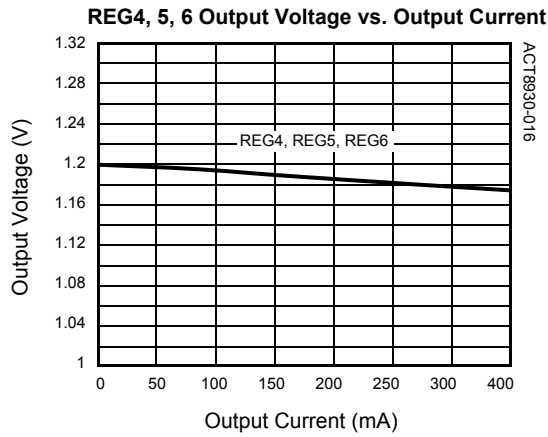
TYPICAL PERFORMANCE CHARACTERISTICS CONT'D

($T_A = 25^\circ\text{C}$, unless otherwise specified.)



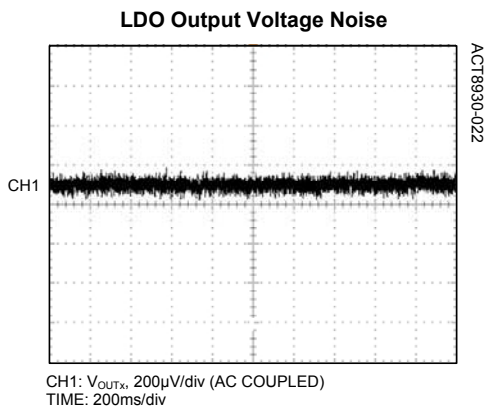
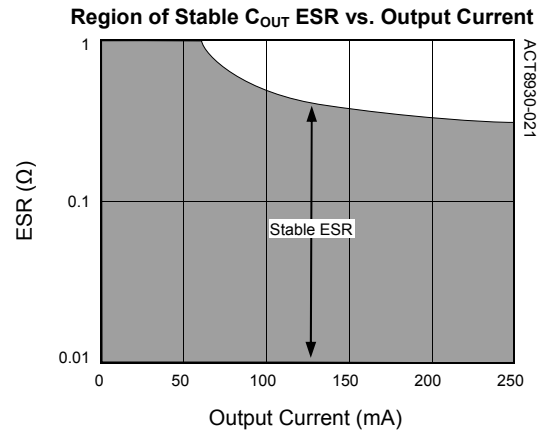
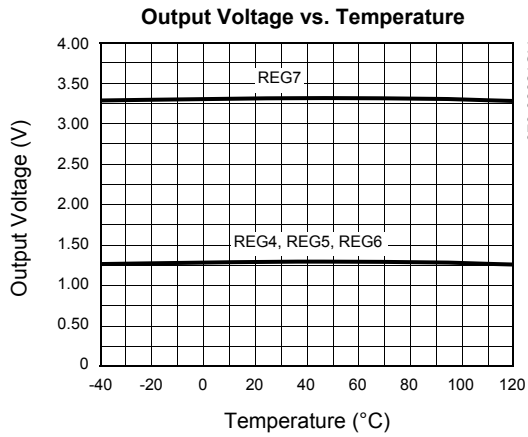
TYPICAL PERFORMANCE CHARACTERISTICS CONT'D

($T_A = 25^\circ\text{C}$, unless otherwise specified.)



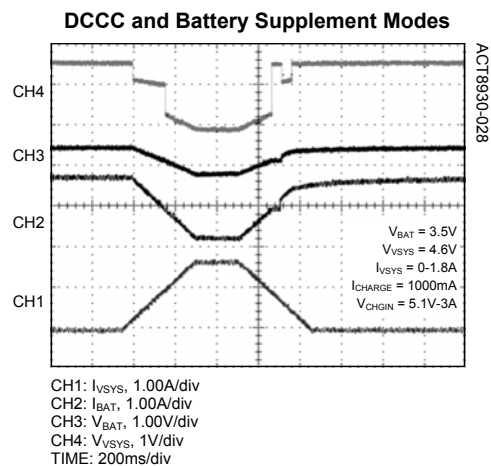
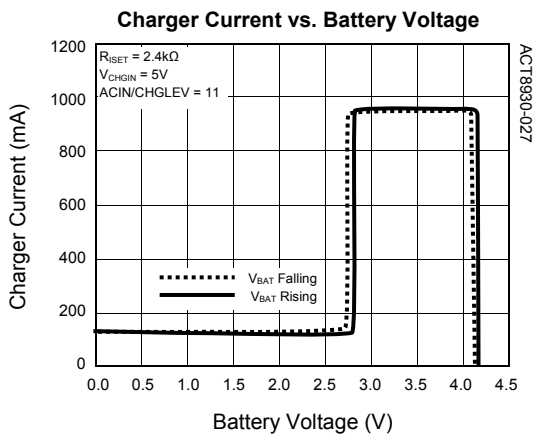
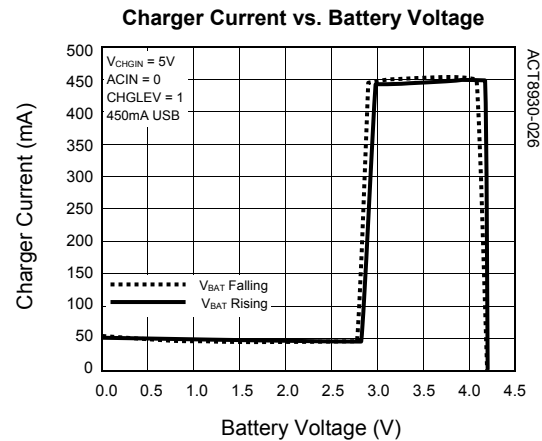
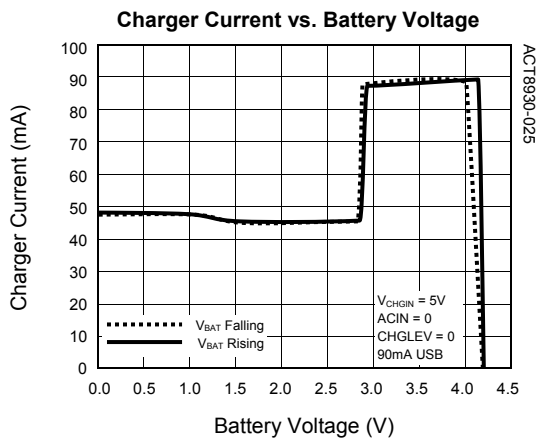
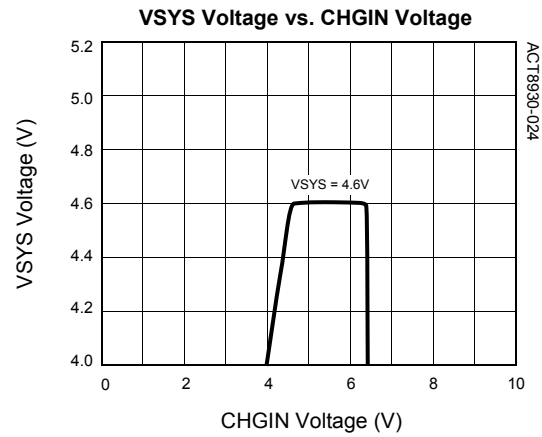
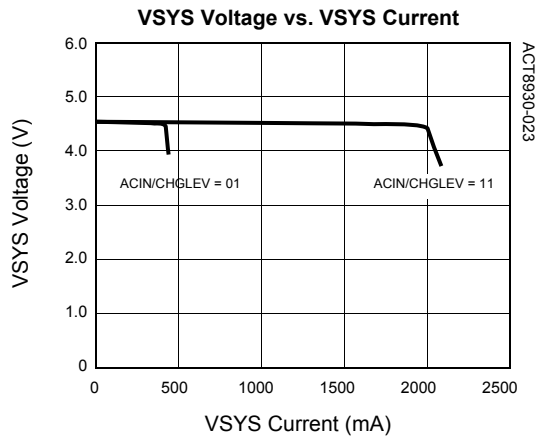
TYPICAL PERFORMANCE CHARACTERISTICS CONT'D

($T_A = 25^\circ\text{C}$, unless otherwise specified.)



TYPICAL PERFORMANCE CHARACTERISTICS CONT'D

($T_A = 25^\circ\text{C}$, unless otherwise specified.)



TYPICAL PERFORMANCE CHARACTERISTICS CONT'D

(T_A = 25°C, unless otherwise specified.)

